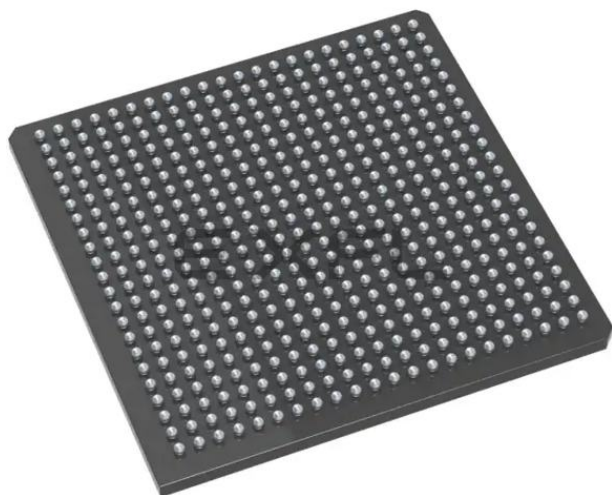




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Understanding [Embedded - FPGAs \(Field Programmable Gate Array\)](#)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details

Product Status	Active
Number of LABs/CLBs	-
Number of Logic Elements/Cells	56340
Total RAM Bits	1869824
Number of I/O	267
Number of Gates	-
Voltage - Supply	1.14V ~ 2.625V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 100°C (TJ)
Package / Case	484-BGA
Supplier Device Package	484-FPBGA (23x23)
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/m2gl050t-fg484i

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1 Revision History

The revision history describes the changes that were implemented in the document. The changes are listed by revision, starting with the most current publication.

1.1 Revision 11.0

The following is a summary of the changes in revision 11.0 of this document.

- Updated Table 24, page 22 with minimum and maximum values for input current low and high (SAR 73114 and 80314).
- Added Non-Deterministic Random Bit Generator (NRBG) Characteristics, page 106 (SAR 73114 and 79517).
- Added 060 device in Table 282, page 110 (SAR 79860).
- Added DEVRST_N to Functional Times, page 116 (SAR 73114).
- Added Cryptographic Block Characteristics, page 106 (SAR 73114 and 79516).
- Update Table 296, page 121 with VTX-AMP details (SAR 81756).
- Update note in Table 297, page 122 (SAR 74570 and 80677).
- Update Table 298, page 122 with generic EPCS details (SAR 75307).
- Added Table 308, page 129 (SAR 50424).

1.2 Revision 10.0

The following is a summary of the changes in revision 10.0 of this document.

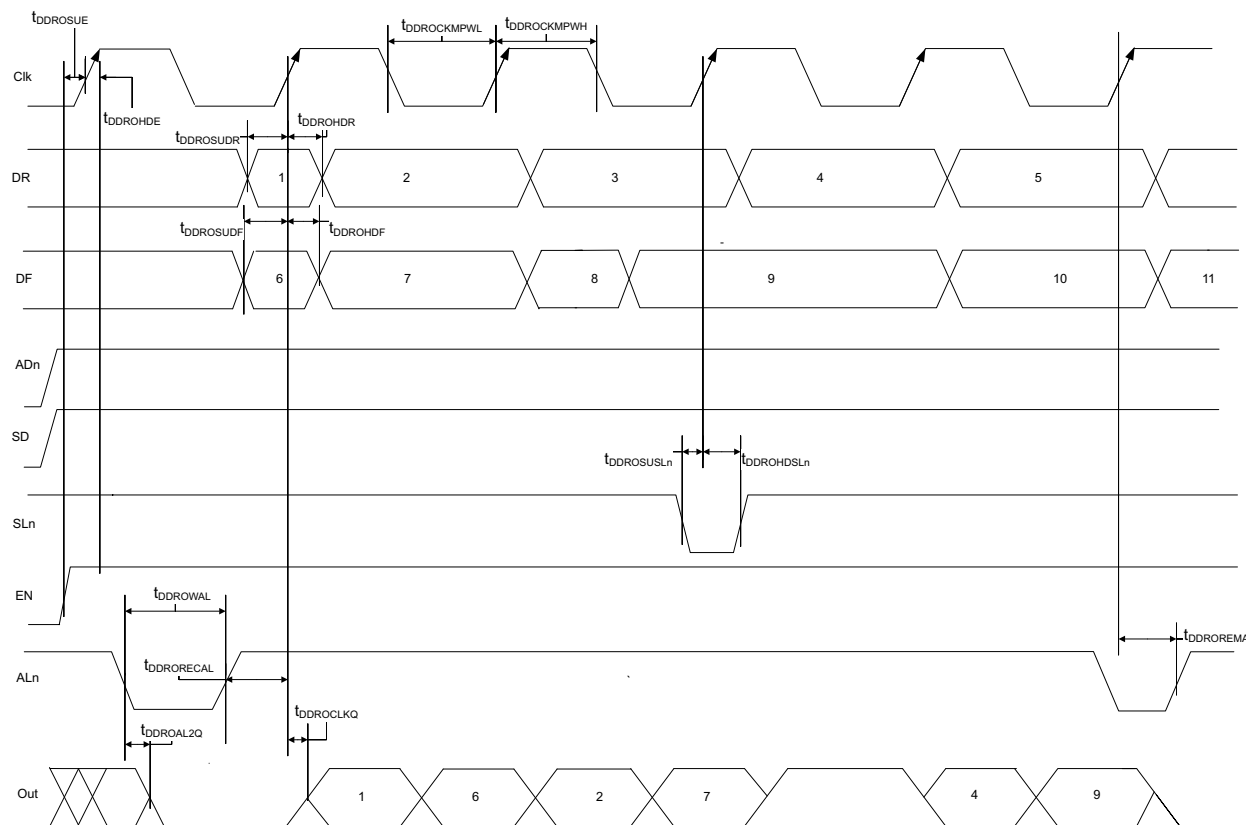
- The Surge Current on VDD during DEVRST_B Assertion and Surge Current on VDD during Digest Check using System Services tables were deleted and added reference to *AC393: Board Design Guidelines for SmartFusion2 SoC and IGLOO2 FPGAs Application Note*. (SAR 76865 and 76623).
- Added 060 device in Table 4, page 6 (SAR 76383).
- Updated Table 24, page 22 for ramp time input (SAR 72103).
- Added 060 device details in Table 284, page 112 (SAR 74927).
- Updated Table 290, page 116 for name change (SAR 74925).
- Updated Table 283, page 111 for 060 FG676 Package details (SAR 78849).
- Updated Table 305, page 126 for SmartFusion2 and Table 310, page 129 for IGLOO2 for SPI timing and Fmax (SAR 56645, 75331).
- Updated Table 293, page 119 for Flash*Freeze entry and exit times (SAR 75329, 75330).
- Updated Table 297, page 122 for RX-CID information (SAR 78271).
- Added Table 8, page 8 and Figure 1, page 9 (SAR 78932).
- Updated Table 223, page 76 for timing characteristics and Table 224, page 77 (SAR 75998).
- Added SRAM PUF, page 105 (SAR 64406).
- Added a footnote on digest cycle in Table 5, page 7 (SAR 79812).

1.3 Revision 9.0

The following is a summary of the changes in revision 9.0 of this document.

- Added a note in Table 5, page 7 (SAR 71506).
- Added a note in Table 6, page 8 (SAR 74616).
- Added a note in Figure 3, page 17 (SAR 71506).
- Updated Quiescent Supply Current for 060 in Table 11, page 12 and Table 12, page 13 (SAR 74483).
- Updated programming currents for 060 in Table 13, page 13, Table 14, page 13, and Table 15, page 14.
- Added DEVRST_B assertion tables (SAR 74708).
- Updated I/O speeds for LVDS 3.3 V in Table 18, page 19 and Table 21, page 20 (SAR 69829).
- Updated Table 24, page 22 (SAR 69418).
- Updated Table 25, page 22, Table 26, page 23, Table 27, page 23 (SAR 74570).
- Updated all AC/DC table to link to the Input Capacitance, Leakage Current, and Ramp Time, page 22 for reference (SAR 69418).

Figure 13 • Output DDR Timing Diagram



2.3.9.5 Timing Characteristics

The following table lists the output DDR propagation delays in worst commercial-case conditions when $T_J = 85^\circ\text{C}$, $V_{DD} = 1.14\text{ V}$.

Table 222 • Output DDR Propagation Delays

Symbol	Description	Measuring Nodes (from, to)	1	Std	Unit
T _{DDROCLKQ}	Clock-to-out of DDR for output DDR	E, G	0.263	0.309	ns
T _{DDROSUDF}	Data_F data setup for output DDR	F, E	0.143	0.168	ns
T _{DDROSUDR}	Data_R data setup for output DDR	A, E	0.19	0.223	ns
T _{DDROHDF}	Data_F data hold for output DDR	F, E	0	0	ns
T _{DDROHDR}	Data_R data hold for output DDR	A, E	0	0	ns
T _{DDROSUE}	Enable setup for input DDR	B, E	0.419	0.493	ns
T _{DDROHE}	Enable hold for input DDR	B, E	0	0	ns
T _{DDROSUSLN}	Synchronous load setup for input DDR	D, E	0.196	0.231	ns
T _{DDROHSLN}	Synchronous load hold for input DDR	D, E	0	0	ns
T _{DDROAL2Q}	Asynchronous load-to-out for output DDR	C, G	0.528	0.621	ns
T _{DDROREMA}	Asynchronous load removal time for output DDR	C, E	0	0	ns
T _{DDRORECA}	Asynchronous load recovery time for output DDR	C, E	0.034	0.04	ns

Table 262 • SmartFusion2 Cortex-M3 ISP Programming (Fabric Only)

M2S/M2GL Device	Image size Bytes	Authenticate	Program	Verify	Unit
005	302672	6	41	8	Sec
010	568784	10	48	14	Sec
025	1223504	21	61	29	Sec
050	2424832	39	82	50	Sec
060	2418896	44	87	54	Sec
090	3645968	66	112	79	Sec
150	6139184	108	162	128	Sec

Table 263 • SmartFusion2 Cortex-M3 ISP Programming (eNVM Only)

M2S/M2GL Device	Image size Bytes	Authenticate	Program	Verify	Unit
005	137536	3	64	4	Sec
010	274816	4	104	7	Sec
025	274816	4	104	8	Sec
050	2,78,528	4	102	8	Sec
060	268480	6	102	8	Sec
090	544496	10	179	15	Sec
150	544496	10	180	15	Sec

Table 264 • SmartFusion2 Cortex-M3 ISP Programming (Fabric and eNVM)

M2S/M2GL Device	Image size Bytes	Authenticate	Program	Verify	Unit
005	439296	9	83	11	Sec
010	842688	15	129	21	Sec
025	1497408	26	143	35	Sec
050	2695168	43	163	55	Sec
060	2686464	48	165	60	Sec
090	4190208	75	266	91	Sec
150	6682768	117	318	141	Sec

Table 276 • Cryptographic Block Characteristics **(continued)**

Service	Conditions	Timing	Unit
SHA256	512 bits	540	kbps
	1024 bits	780	kbps
	2048 bits	950	kbps
	24 kbits	1140	kbps
HMAC	512 bytes	820	kbps
	1024 bytes	890	kbps
	2048 bytes	930	kbps
	24 kbytes	980	kbps
KeyTree		1.8	ms
Challenge-response	PUF = OFF	25	ms
	PUF = ON	7	ms
ECC point multiplication		590	ms
ECC point addition		8	ms

1. Using cypher block chaining (CBC) mode.

2.3.19 Crystal Oscillator

The following table describes the electrical characteristics of the crystal oscillator in the IGLOO2 FPGA and SmartFusion2 SoC FPGAs.

Table 277 • Electrical Characteristics of the Crystal Oscillator High Gain Mode (20 MHz)

Parameter	Symbol	Min	Typ	Max	Unit	Condition
Operating frequency	FXTAL		20		MHz	
Accuracy	ACCXTAL			0.0047	%	005, 010, 025, 050, 060, and 090 devices
				0.0058	%	150 devices
Output duty cycle	CYCXTAL		49 51	47 53	%	
Output period jitter (peak to peak)	JITPERXTAL		200	300	ps	
Output cycle to cycle jitter (peak to peak)	JITCYCXTAL		200	300	ps	010, 025, 050, and 060 devices
			250	410	ps	150 devices
			250	550	ps	005 and 090 devices
Operating current	IDYNXTAL		1.5		mA	010, 050, and 060 devices
			1.65		mA	005, 025, 090, and 150 devices
Input logic level high	VIHXTAL	0.9 V _{PP}			V	
Input logic level low	VILXTAL			0.1 V _{PP}	V	

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